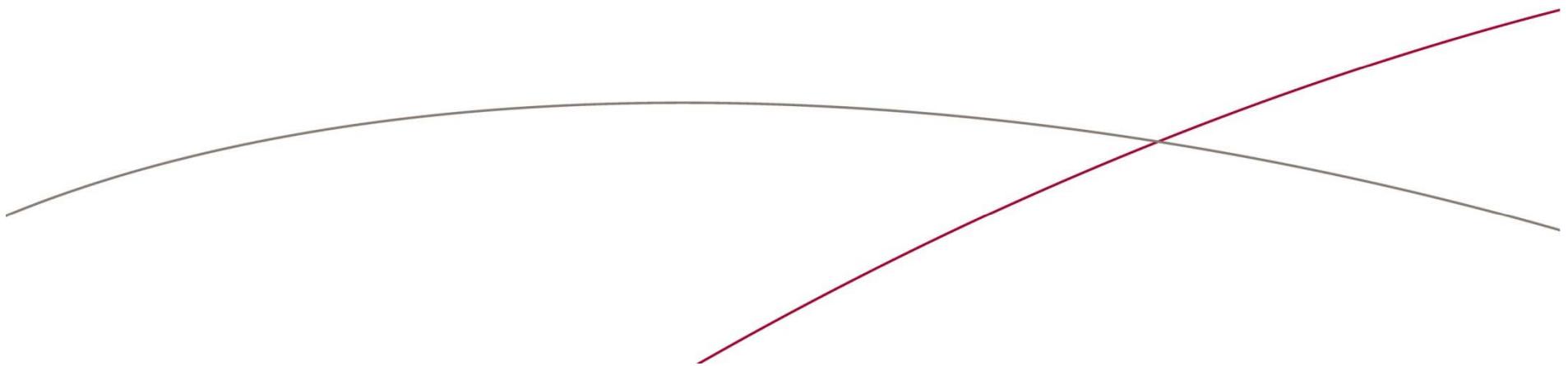


Ultra Low Power Radio

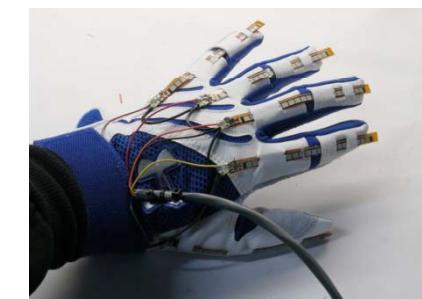
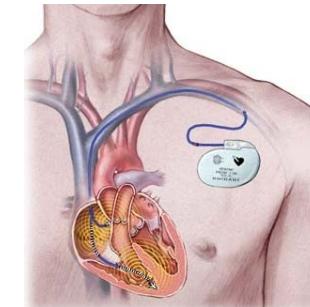
Henrik Sjöland

Department of Electrical and Information Technology
Lund University, Sweden



Applications

- Medical implants
- Hearing aids
- Pacemakers
- Watches
- Video game controls
- Active RFID tags
- Remote controls
- Keys
- Body area networks
- Sensor networks
- etc.



In some applications the battery must last the equipment lifetime!



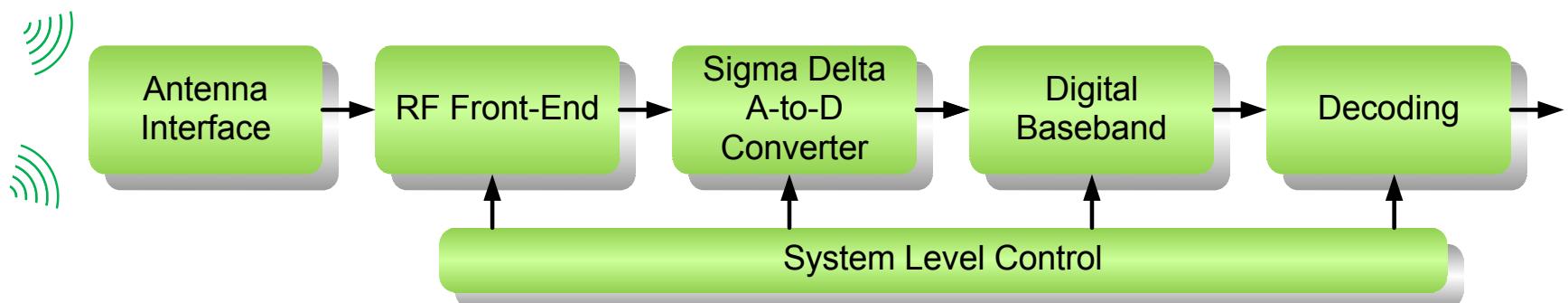
Wireless Communication for Ultra Portable Devices

SSF Framework Program

- 5-year project, started 2008
- 6 PhD Students
- 9 Senior Researchers

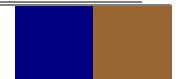
Scope

- Receiver chain from antenna to decoder
- Medium Access Control (MAC)
- Propagation in bio-applications



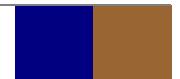
Targets

- 1mW in active mode
- 1uW in standby
- 1mm² chip area in 65nm CMOS
- 250 kbit/s
- Final goal: Demonstration of antenna + chip in medical implant mock-up



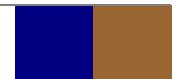
System Parameters

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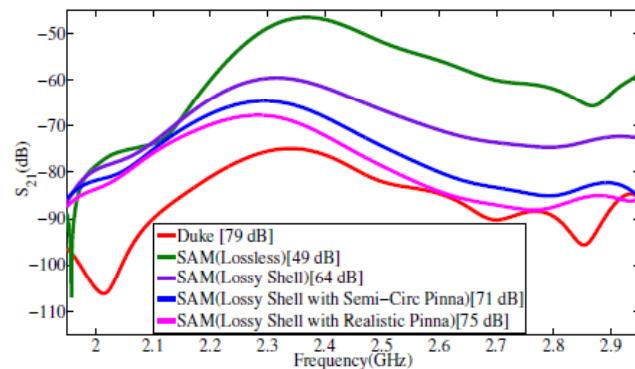
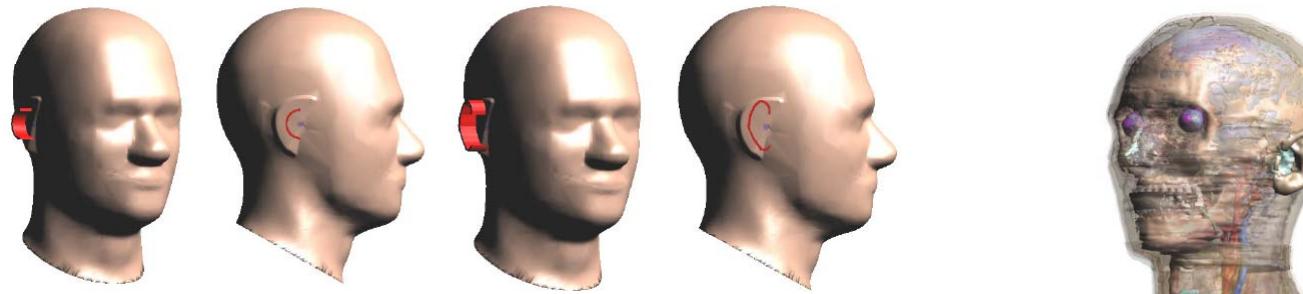
Sensitivity Calculation

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Antennas and Propagation

Ear-to-Ear: Effect of Outer Ears and Lossy Skin



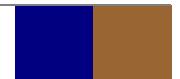
Lossy skin and outer ears must be included in the model
About 80dB total path loss worst case



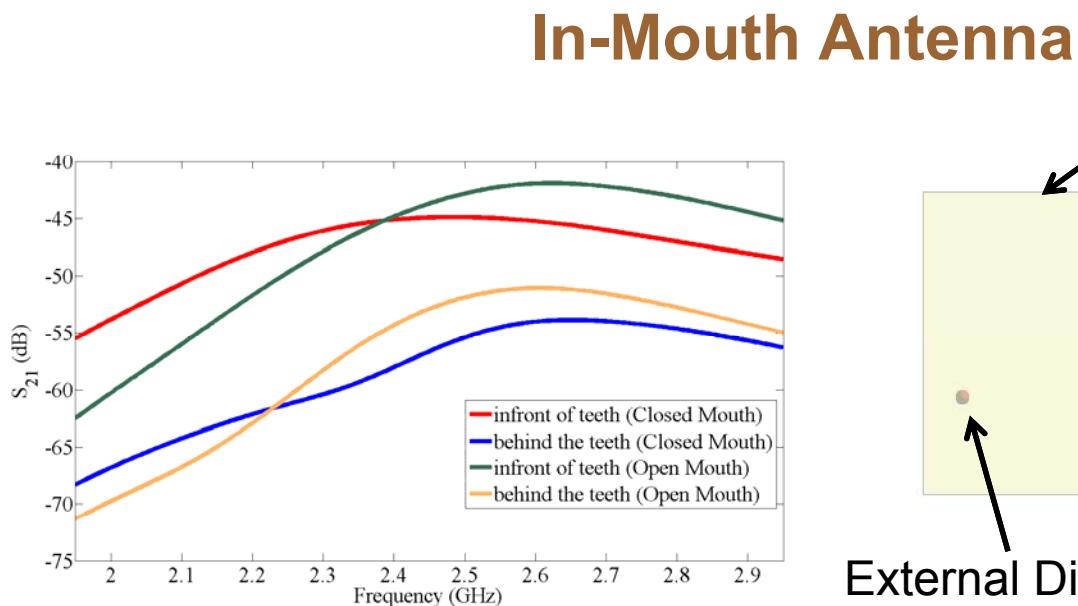
Antennas and Propagation

Ear-to-Ear: Meaurements

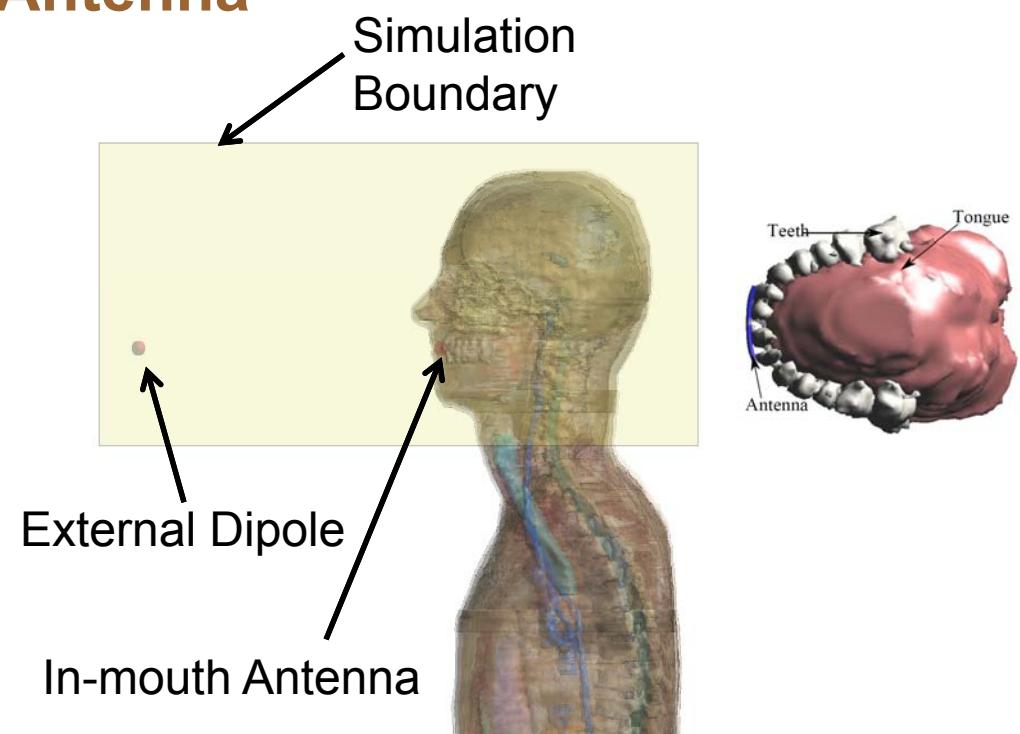
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Antennas and Propagation



About 60dB path loss worst case



Distance centre of head to
external antenna = 400 mm

In cooperation with
Aalborg University

RF front-end

Minimize chip area => Inductorless design

Ultra low power => Weak inversion operation

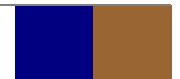
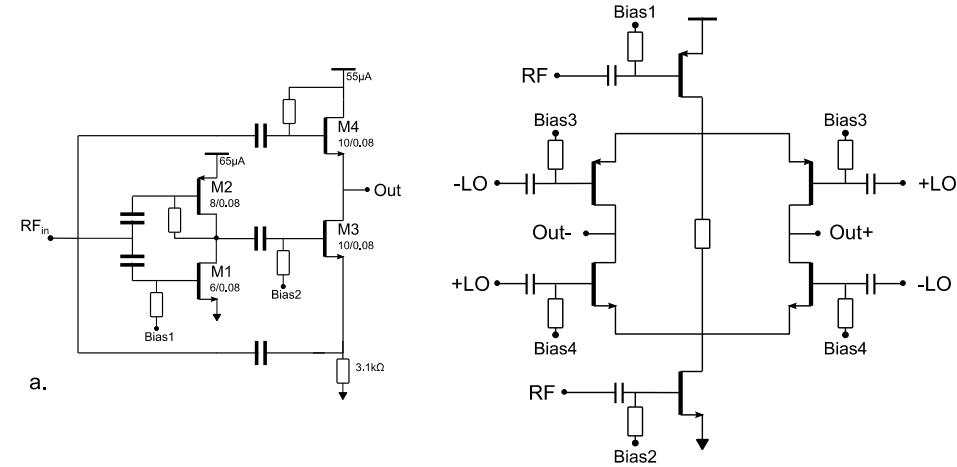
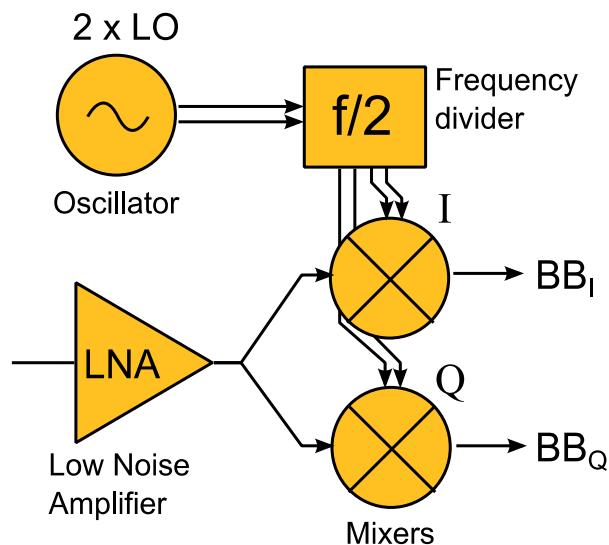
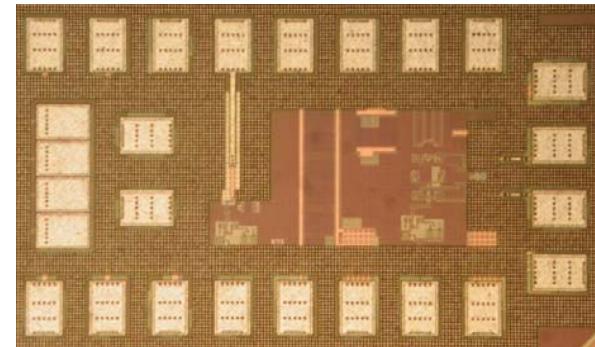
Inductorless Weak Inversion Front-End in 65nm CMOS
Performance?

- Power
- Frequency
- Gain
- Noise figure
- Linearity
- Input impedance



RF front-end

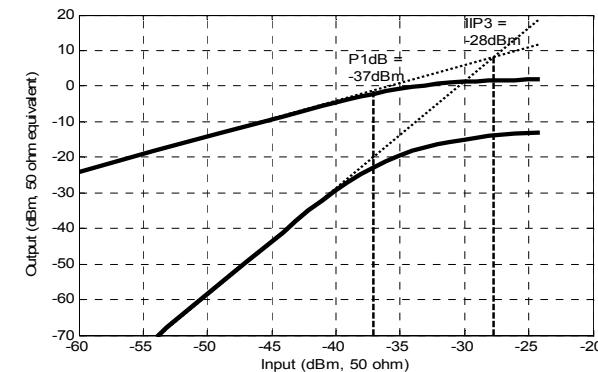
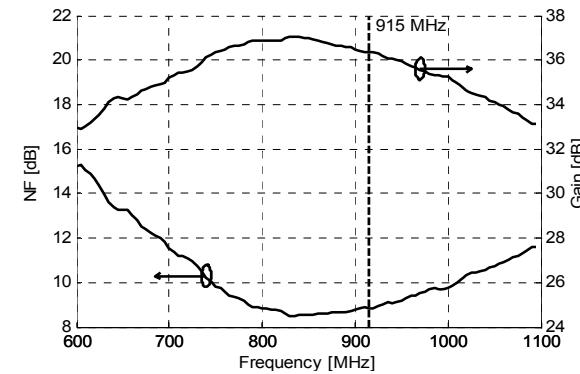
- Inductorless design
- Feedback LNA
- Current reuse active mixers



RF front-end

Measurement Results

- LNA + Frequency divider + Quadrature mixer
- Ultra low power: **280 μ W**
- Active area: 0.016mm² in 65nm CMOS
- Measurements:
 - 915 MHz (limited by frequency divider)
 - 200 Ω input impedance
 - 30dB voltage gain
 - 9dB NF**
 - 100kHz 1/f noise corner
 - 37 dBm CP_{1dB}
 - 28 dBm IIP3
 - < -95dBm LO to RF leakage
 - > -5dBm IIP2
- ESSCIRC 2011



RF front-end

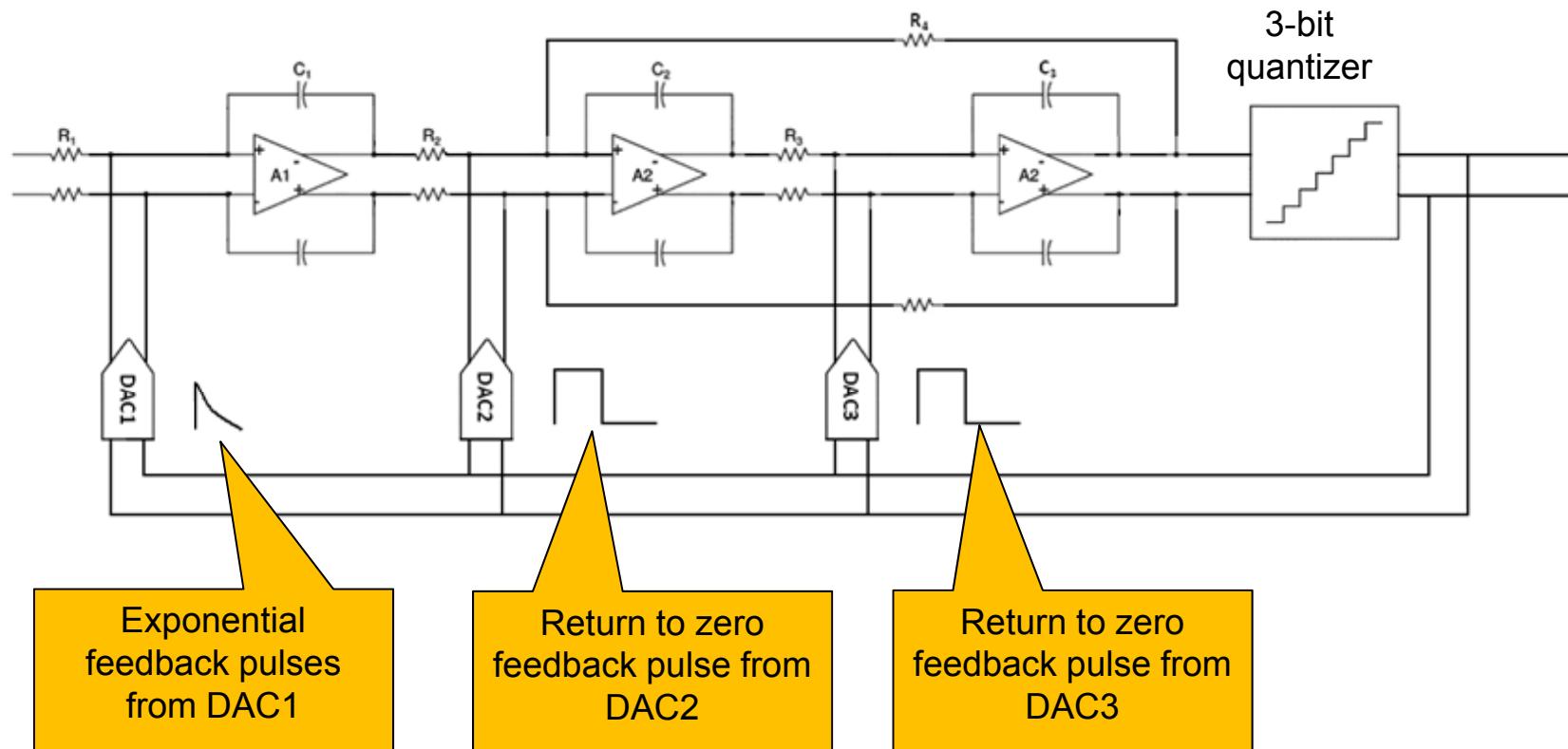
Quadrature LO Generation

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Analog to Digital Converter

- Continuous-Time (CT) $\Delta\Sigma$ -ADC eliminates analog channel select filter
- 3rd order modulator with 3 bit quantizer



Analog to Digital Converter

Measurement Results

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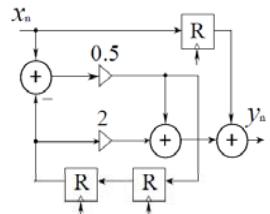
Digital Baseband

- Combined Decimation and Channel Select Filter
- Sharp filtering in digital domain
- Challenge: Weak inversion design with high throughput
- Chain of half-band filters & decimate by 2

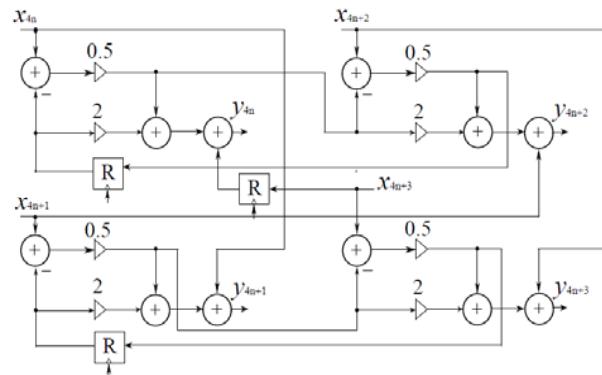


Digital Baseband

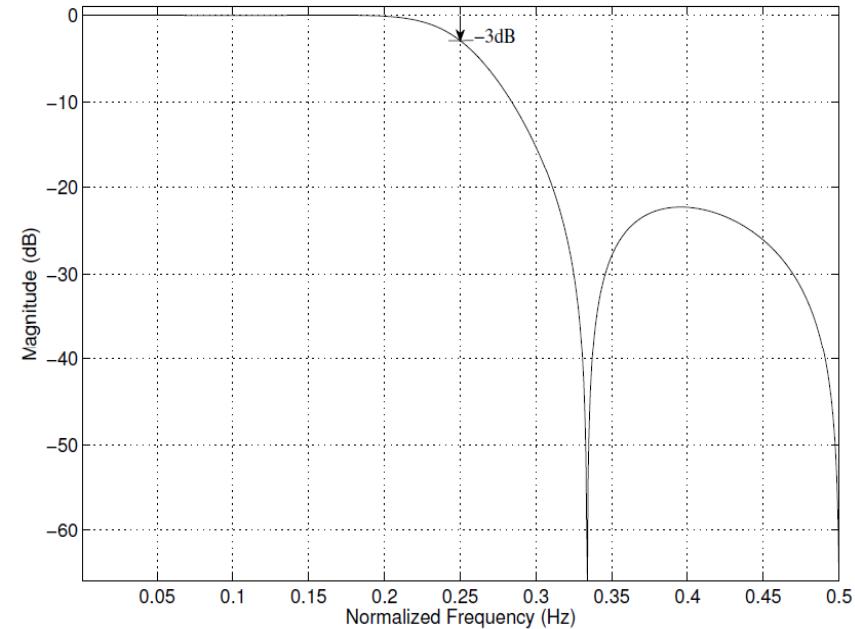
Half-band filters



Original (ORG)



Unfolded by 4 (UF4)

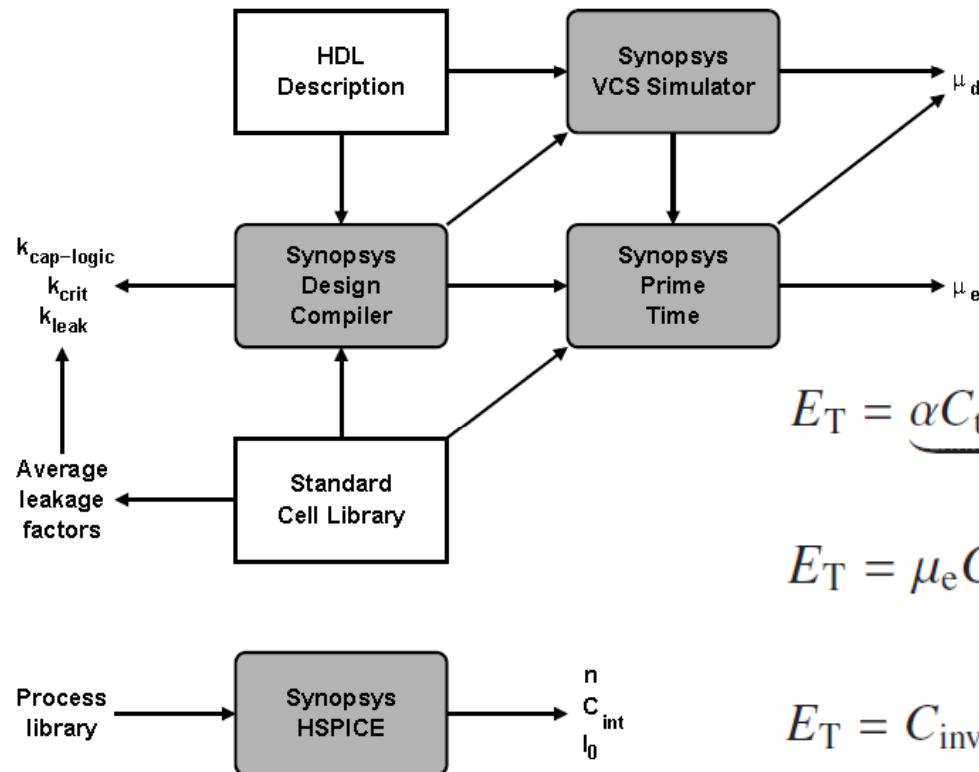


$$H_z = \frac{1 + 2z^{-1} + 2z^{-2} + z^{-3}}{2 + z^{-2}}$$



Digital Baseband

High-Level Sub-V_T Energy Model



$$E_T = \underbrace{\alpha C_{tot} V_{DD}^2}_{E_{dyn}} + \underbrace{I_{leak} V_{DD} T_{clk}}_{E_{leak}} + \underbrace{I_{peak} t_{sc} V_{DD}}_{E_{sc}}$$

$$E_T = \mu_e C_{inv} k_{cap} V_{DD}^2 + k_{leak} I_0 V_{DD} T_{clk}$$

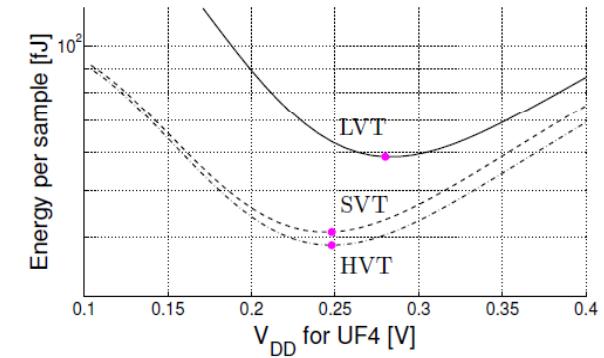
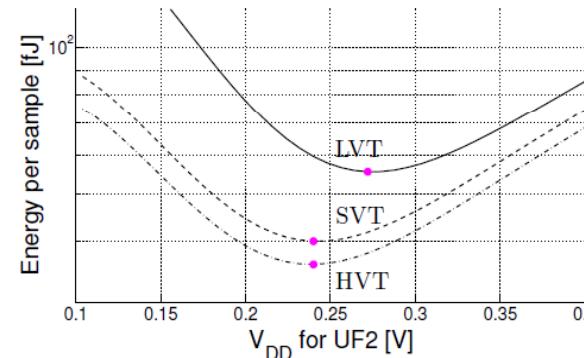
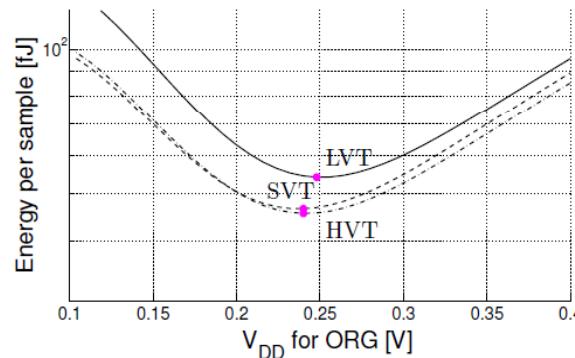
$$E_T = C_{inv} V_{DD}^2 \left[\mu_e k_{cap} + k_{crit} k_{leak} e^{-V_{DD}/(nU_t)} \right]$$

In cooperation with EPFL

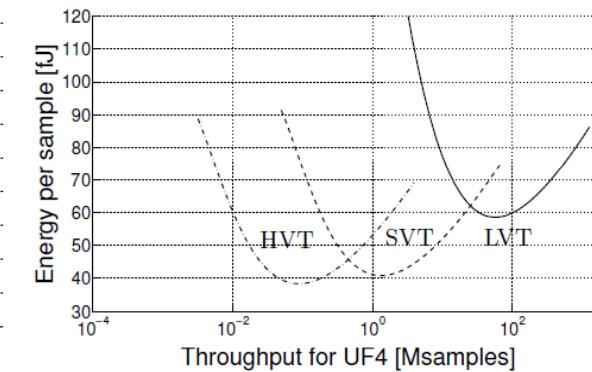
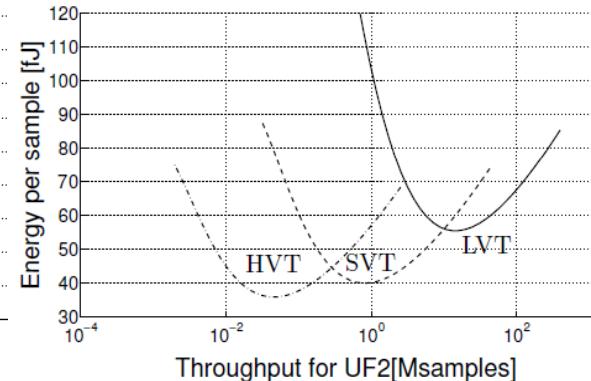
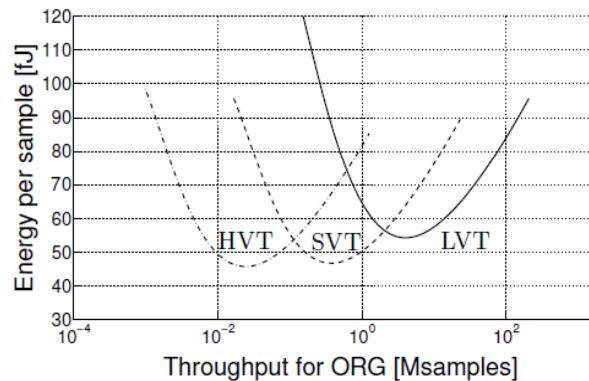


Digital Baseband

Energy vs V_{DD}

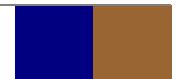
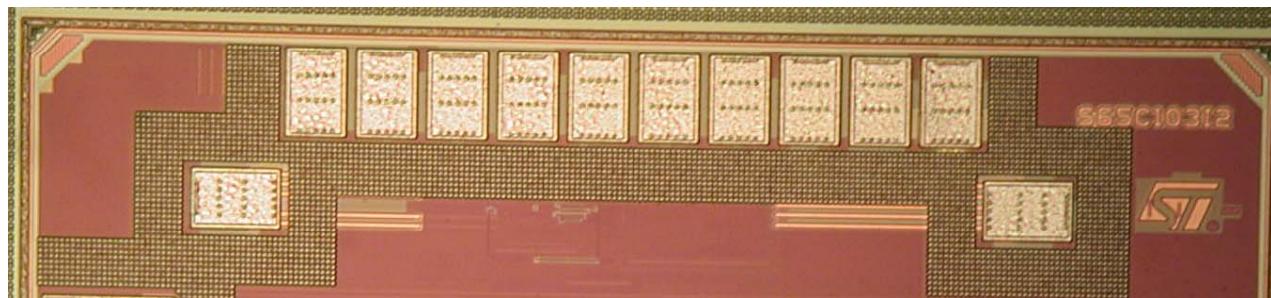
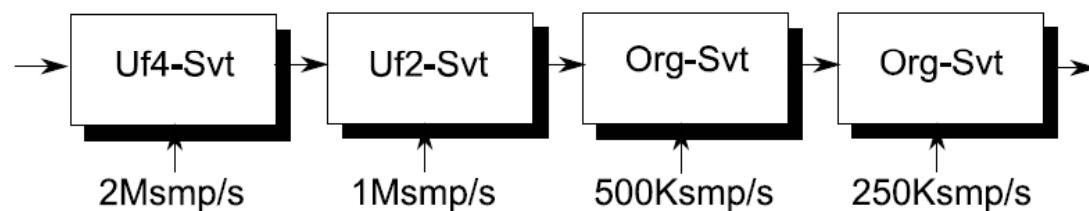


Energy vs Throughput



Digital Baseband

First chip ready measurements to start



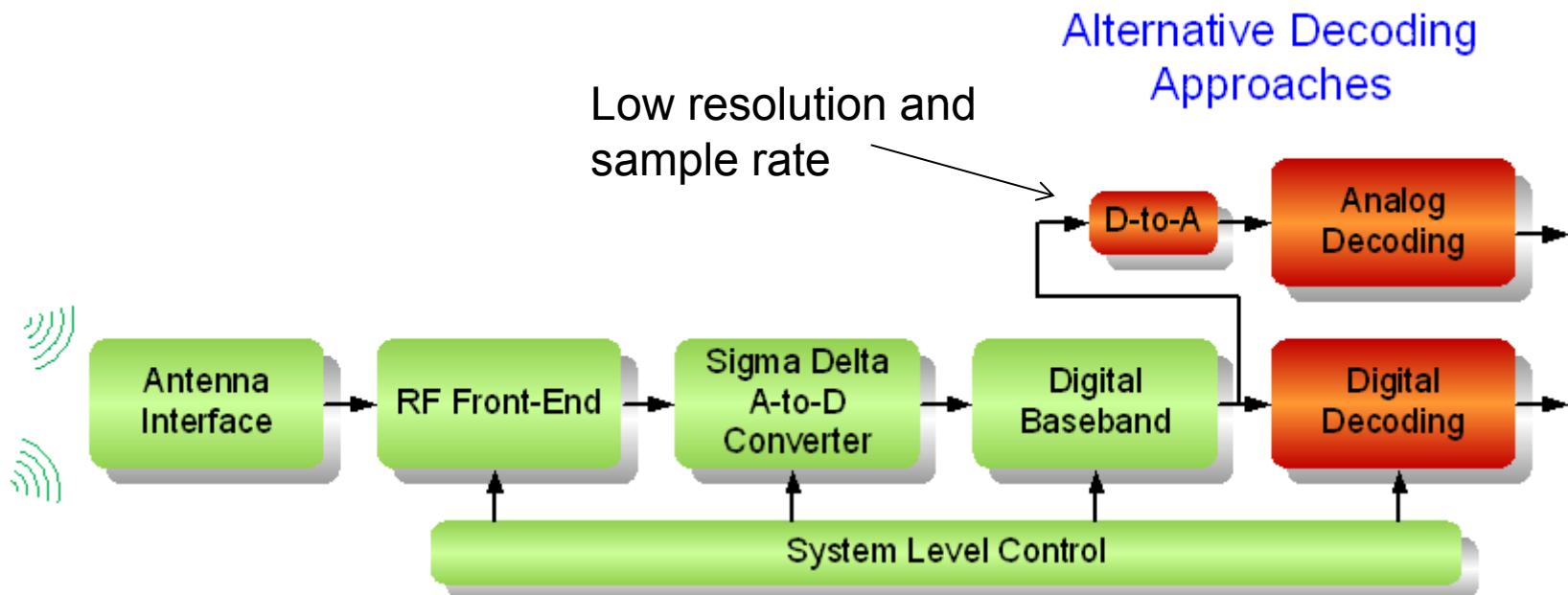
Digital Baseband

Next tape-out: Modified Filter Chain + demodulation
Suppression of $\Delta\Sigma$ noise & sharp channel filtering

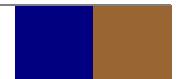
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Analog Decoder



Key advantage of analog decoder: Ultra low power consumption



Analog Decoder

Advantages and Challenges

- + Fewer transistors than digital implementation
- + Computations performed in continuous time
- + High throughput by parallel computations
- + Power efficiency improvements up to two orders of magnitude have been reported
- Weak inversion operation => sensitive to V_{Th} mismatch
- Increased transistor sizes needed
- Complex analog circuit => Long simulation
- Stacked transistors in multipliers => Hard to reduce supply



Analog Decoder

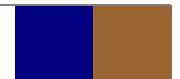
Investigated Analog Decoders with digital I/O

Hamming decoder

- Transistor level simulations
- Consumes 20 μW at 250 kb/s
- Coding gain: 1.5 dB at BER 10^{-3}

(7,5) Convolutional decoder

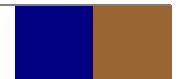
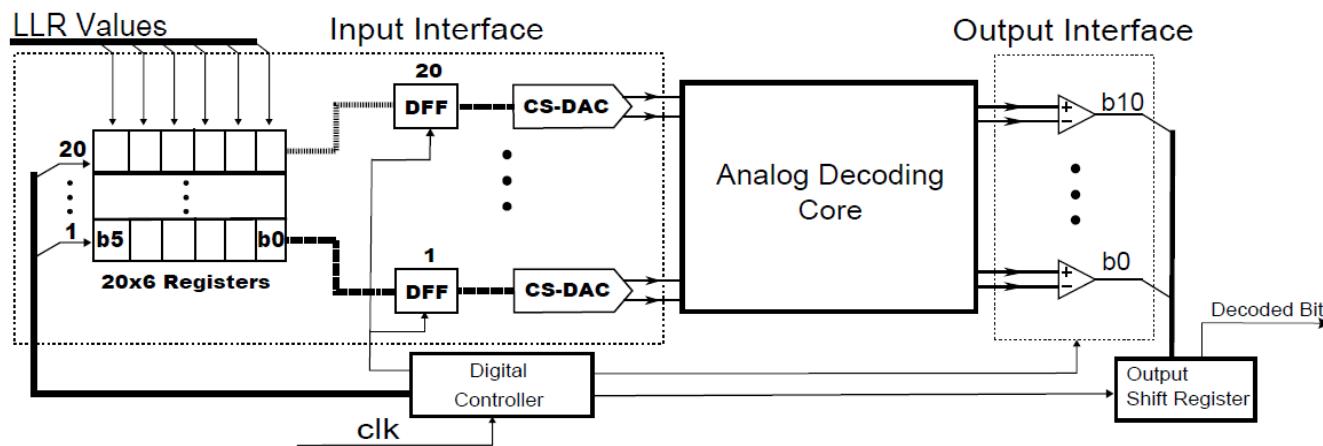
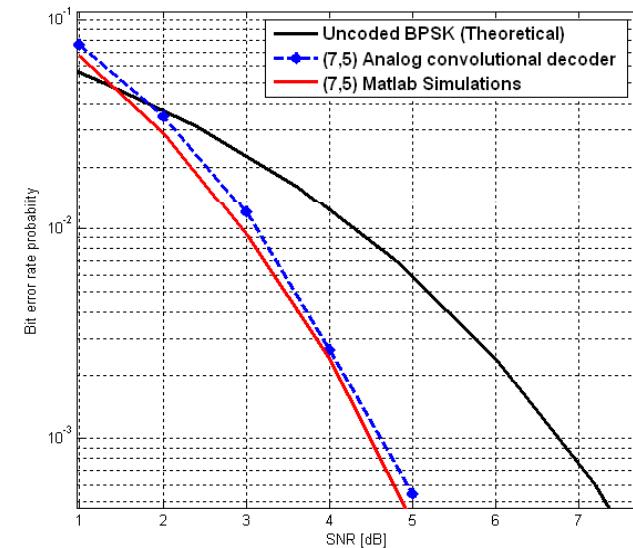
- Post layout simulations
- Consumes 50 μW at 250 kb/s
- Coding gain: 2.1 dB at BER 10^{-3}



Analog Decoder

(7,5) Convolutional tailbiting decoder

- Digital I/O (not optimized resolution/power)
- 47uW total at 250kbit/s
- 15uW in analog decoder core



Medium Access Control (MAC)

- Focus on low-traffic conditions
- Minimize energy waste
- Provide sufficient quality of service
- Sources of energy waste
 - Idle listening
 - Overhearing
 - Data overhead
 - Collision

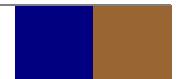
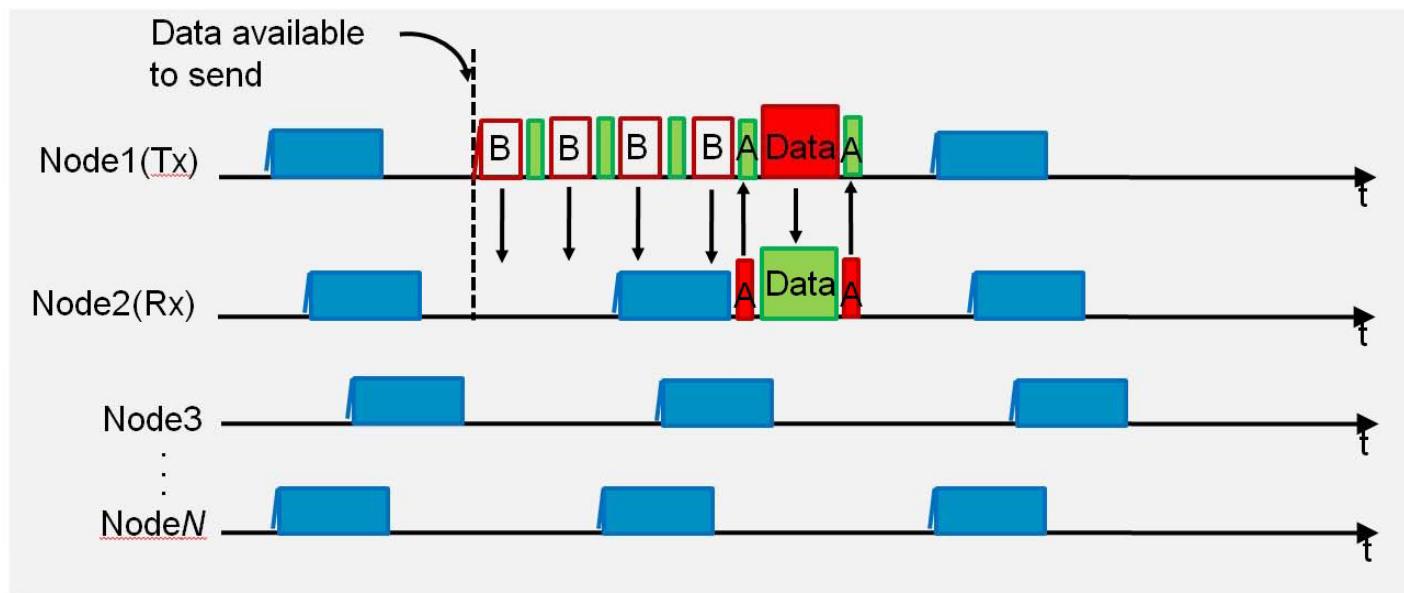
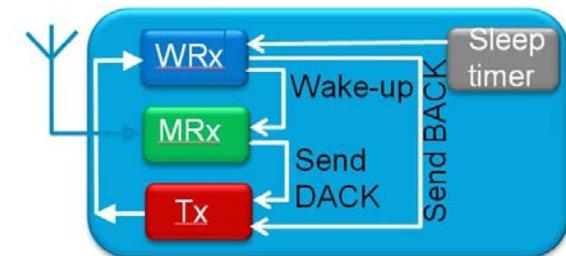
Duty-cycled MAC protocols are a
common approach to reduce idle listening



Medium Access Control (MAC)

DCW-MAC scheme

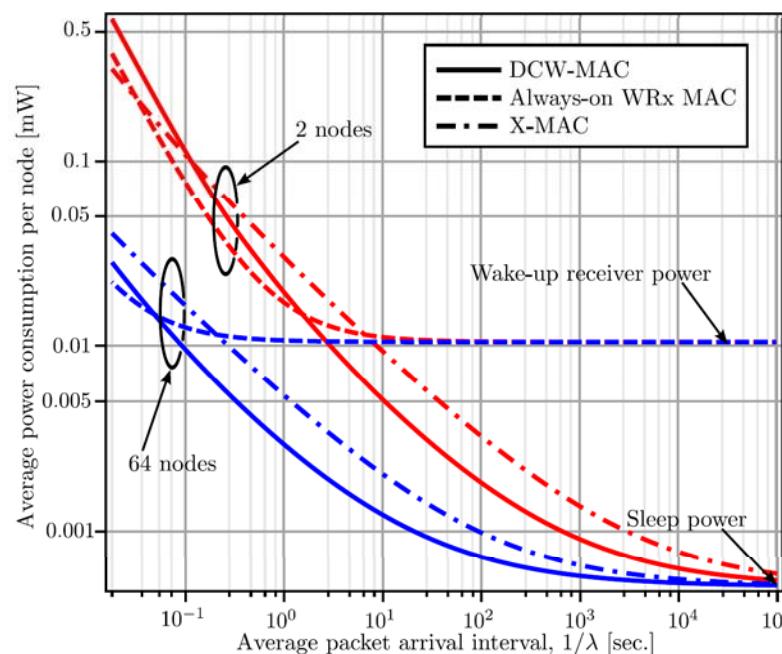
Combines ultra low-power WRxs and duty-cycled listening.



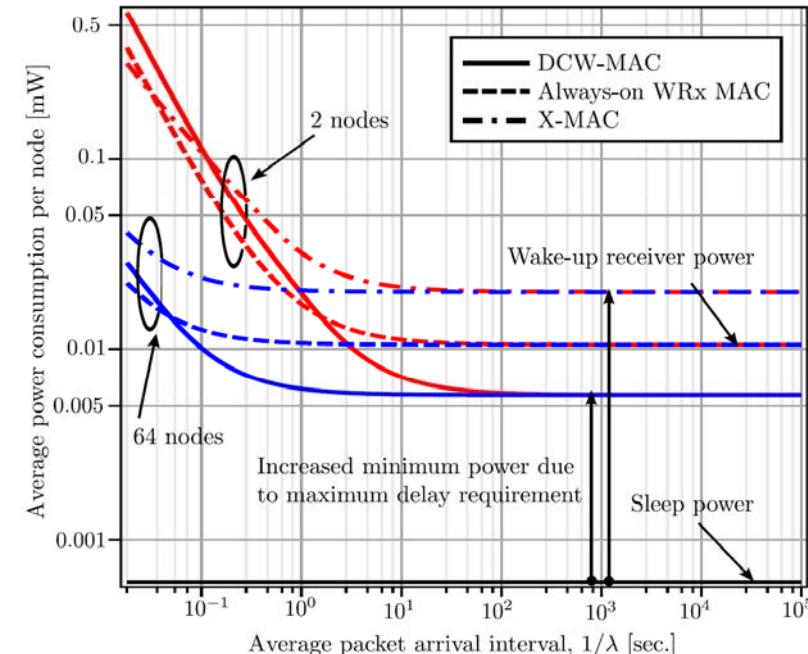
Medium Access Control (MAC)

Numerical results, perfect beacon detection

a) No delay requirement



b) With delay requirement



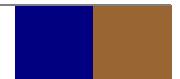
Excellent performance in low traffic with maximum delay requirement



Medium Access Control (MAC)

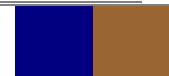
Effect of imperfect beacon detection

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Future Plans

- Measure digital filter and analog decoder
- 50Ω RF sent for fabrication
- More system simulations & investigations
- Wake-up receiver
- New application: Mouth keyboard
- Co-design of RF+ADC
- Baseband including time synchronization
- ... Demo of complete receiver chip + antenna



Research Team

Senior Researchers:

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Piero Andreani
Ove Edfors
Anders Johansson
Peter Nilsson
Joachim Rodrigues
Markus Törmänen
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Rohit Chandra
Dejan Radjen
Yasser Sherazi
Reza Meraji
Nafiseh Mazloum



Acknowledgments

Many thanks to:



&
Cooperation partners

Questions?

